SLLS009D - OCTOBER 1985 - REVISED MAY 1995

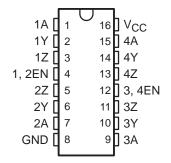
- Meet or Exceed the Requirements of ANSI Standard EIA/TIA-422-B and ITU Recommendation V.11
- Designed to Operate Up to 20 Mbaud
- 3-State TTL-Compatible Outputs
- Single 5-V Supply Operation
- High Output Impedance in Power-Off Condition
- Two Pairs of Drivers, Independently Enabled
- Designed as Improved Replacements for the MC3487

### description

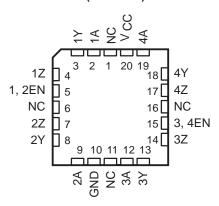
These four differential line drivers are designed for data transmission over twisted-pair or parallel-wire transmission lines. They meet the requirements of ANSI Standard EIA/TIA-422-B and ITU Recommendation V.11 and are compatible with 3-state TTL circuits. Advanced low-power Schottky technology provides high speed without the usual power penalty. Standby supply current is typically only 26 mA. Typical propagation delay time is less than 10 ns, and enable/disable times are typically less than 16 ns.

High-impedance inputs keep input currents low: less than 1  $\mu$ A for a high level and less than 100  $\mu$ A for a low level. The driver circuits can be enabled in pairs by separate active-high enable inputs. The SN55ALS194 and SN75ALS194 are capable of data rates in excess of 20 megabits per second and are designed to operate with the SN55ALS195 and SN75ALS195 quadruple line receivers.

SN55ALS194...J OR W PACKAGE SN75ALS194...D OR N PACKAGE (TOP VIEW)



# SN55ALS194...FK PACKAGE (TOP VIEW)



NC - No internal connection

The SN55ALS194 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to  $125^{\circ}$ C. The SN75ALS194 is characterized for operation from  $0^{\circ}$ C to  $70^{\circ}$ C.

# FUNCTION TABLE (each driver)

INPUTS	OUTPUT	OUTI	PUTS
Α	EN	Υ	Z
Н	Н	Н	L
L	Н	L	Н
Х	L	Z	Z

H = high level, L = low level, X = irrelevant, Z = high impedance

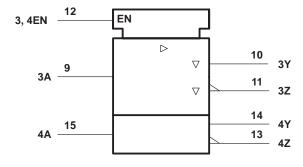


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### logic symbol†

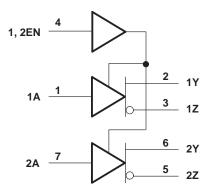
### 1, 2EN ΕN $\nabla$ 3 1Z $\nabla$ 2Y 2Z

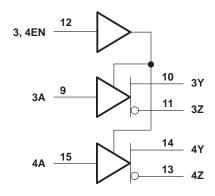


<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

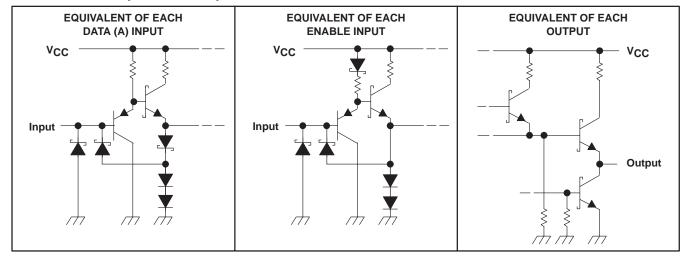
Pin numbers shown are for the D, J, N, and W packages.

### logic diagram (positive logic)





### schematics of inputs and outputs



SLLS009D - OCTOBER 1985 - REVISED MAY 1995

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)		
Input voltage, V <sub>I</sub>		
Output voltage, VO		
Continuous total dissipation		See Dissipation Rating Table
Operating free-air temperature range, TA:	SN55ALS194	– 55°C to 125°C
	SN75ALS194	0°C to 70°C
Storage temperature range, T <sub>stq</sub>		– 65°C to 150°C
Case temperature for 60 seconds, T <sub>C</sub> : FK		
Lead temperature 1,6 mm (1/16 inch) from		
Lead temperature 1,6 mm (1/16 inch) from	n case for 60 seconds: J pack	age 300°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal

#### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D	950 mW	7.6 mW/°C	608 mW	N/A
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
J	1375 mW	11.0 mW/°C	880 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	N/A
W	1000 mW	8.0 mW/°C	640 mW	200 mW

### recommended operating conditions‡

		SN55ALS194			SN	75ALS1	94	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>	upply voltage, VCC		5	5.5	4.75	5	5.25	V
High-level input voltage, V <sub>IH</sub>	All inputs, T <sub>A</sub> = 25°C	2			2			
	A inputs, T <sub>A</sub> = Full range	2			2			V
	EN inputs, T <sub>A</sub> = Full range	2.1			2			
Low-level input voltage, V <sub>IL</sub>				0.8			0.8	V
High-level output current, IOH				- 20			- 20	mA
Lour love love to the state of	T <sub>A</sub> = 25°C			48			48	A
Low-level output current, I <sub>OL</sub>	T <sub>A</sub> = Full range			20			48	mA
Operating free-air temperature, T <sub>A</sub>		- 55		125	0		70	°C

<sup>‡</sup> Full range is  $T_A = -55$ °C to 125°C for SN55ALS194 and  $T_A = 0$ °C to 70°C for SN75ALS194.



### SN55ALS194, SN75ALS194 QUADRUPLE DIFFERENTIAL LINE DRIVERS

SLLS009D - OCTOBER 1985 - REVISED MAY 1995

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONI	MIN	TYP <sup>‡</sup>	MAX	UNIT	
VIK	Input clamp voltage	$V_{CC} = MIN,$	$I_{I} = -18 \text{ mA}$			- 1.5	V
Vou	High-level output voltage	V <sub>CC</sub> = MIN,	SN55ALS194	2.4			V
VOH	nigh-level output voltage	$I_{OH} = -20 \text{ mA}$	SN75ALS194	2.5			V
VOL	Low-level output voltage	$V_{CC} = MIN,$	$I_{OL} = MAX$			0.5	V
VO	Output voltage	I <sub>O</sub> = 0		0		6	V
IVOD1	Differential output voltage	IO = 0		1.5		6	V
IVOD2I	Differential output voltage			1/2 V <sub>OD1</sub> or 2§			V
Δ V <sub>OD</sub>	Change in magnitude of differential output voltage¶	R <sub>L</sub> = 100 Ω,	$L_L = 100 Ω$ , See Figure 1			± 0.4	V
Voc	Common-mode output voltage					± 3	V
∆IVocI	Change in magnitude of common-mode output voltage¶					± 0.4	V
lo.	Output current with power off	V <sub>CC</sub> = 0	V <sub>O</sub> = 6 V			100	μА
Ю	Output current with power on	vCC = 0	$V_0 = -0.25 \text{ V}$			- 100	μΑ
		V <sub>CC</sub> = MAX,	$V_0 = 2.7 \text{ V}$			100	
loz	High-impedance-state output current	Output enables at 0.8 V	V <sub>O</sub> = 0.5 V			<b>– 100</b>	μΑ
lį	Input current at maximum input voltage	$V_{CC} = MAX$ ,	V <sub>I</sub> = 5.5 V			100	μΑ
lіН	High-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 2.7 V			50	μΑ
I <sub>I</sub> L	Low-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 0.5 V			- 200	μΑ
los	Short-circuit output current#	$V_{CC} = MAX$ ,	V <sub>I</sub> = 2 V	- 40		- 140	mA
ICC	Supply current (all drivers)	$V_{CC} = MAX$ ,	All outputs disabled		26	45	mA

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

### switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST	SN	55ALS1	94	SN	94	UNIT	
	PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output	0 45 5		6	13		6	13	ns
tPHL	Propagation delay time, high- to low-level output	C <sub>L</sub> = 15 pF, See Figure 2		9	14		9	14	ns
	Output-to-output skew	Occ Figure 2		3.5	6		3.5	6	ns
t <sub>t</sub> (OD)	Differential output transition time	C <sub>L</sub> = 15 pF, See Figure 3		8	14		8	14	ns
<sup>t</sup> PZH	Output enable time to high level			9	12		9	12	ns
tpzL	Output enable time to low level	$C_L = 15 pF$ ,		12	20		12	20	ns
tPHZ	Output disable time from high level	See Figure 4		9	15		9	14	ns
t <sub>PLZ</sub>	Output disable time from low level			12	15		12	15	ns



<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $TA = 25^{\circ}\text{C}$ .

<sup>§</sup> The minimum  $V_{\mbox{OD2}}$  with a 100- $\Omega$  load is either 1/2  $V_{\mbox{OD1}}$  or 2 V, whichever is greater.

<sup>¶</sup>  $\Delta$  | V<sub>OD</sub> | and  $\Delta$  | V<sub>OC</sub> | are the changes in magnitude of V<sub>OD</sub> and V<sub>OC</sub>, respectively, that occur when the input is changed from a high level to a low level.

<sup>#</sup> Not more than one output should be shorted at a time, and duration of the short circuit should not exceed one second.

SLLS009D - OCTOBER 1985 - REVISED MAY 1995

SYMBOL EQUIVALENTS						
PARAMETER	EIA/TIA-422-B					
0	V <sub>oa</sub> , V <sub>ob</sub>					

 $|I_{xa}|, |I_{xb}|$ 

Vo	V <sub>oa</sub> , V <sub>ob</sub>
VOD1	Vo
∣V <sub>OD2</sub> ∣	$V_t (R_L = 100 \Omega)$
Δ V <sub>OD</sub>	$   V_t  -  \overline{V}_t   $
Voc	V <sub>os</sub>
Δ V <sub>OC</sub>	$ V_{OS} - \overline{V}_{OS} $
los	I <sub>sa</sub>  ,  I <sub>sh</sub>

**DATA SHEET** 

lO

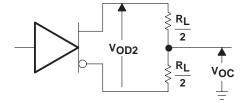
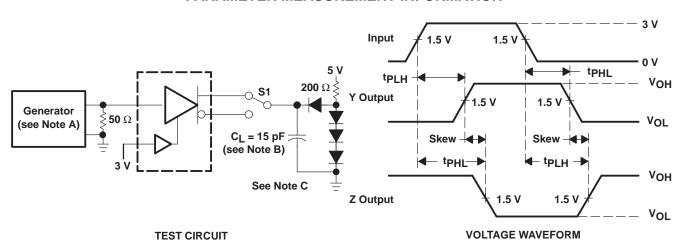


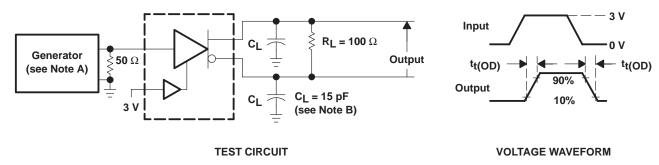
Figure 1. Driver V<sub>OD</sub> and V<sub>OC</sub>

#### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $t_{\Gamma} \le 5$  ns,  $t_{\Gamma} \le 5$  ns, PRR  $\le 1$  MHz, duty cycle  $\le 50\%$ ,  $Z_{O} \approx 50~\Omega$ .
  - B. C<sub>I</sub> includes probe and stray capacitance.
  - C. All diodes are 1N916 or 1N3064.

Figure 2. Test Circuit and Voltage Waveform

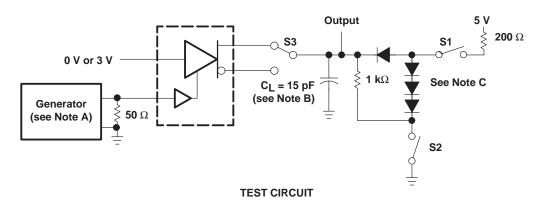


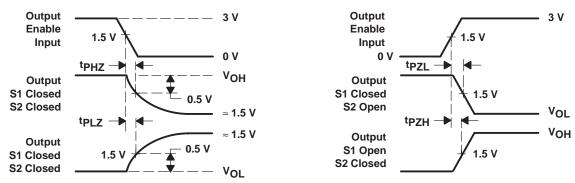
- NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $t_f \le 5$  ns,  $t_f \le 5$  ns, PRR  $\le 1$  MHz, duty cycle  $\le 50\%$ ,  $Z_O \approx 50~\Omega$ .
  - B. C<sub>L</sub> includes probe and stray capacitance.

Figure 3. Differential-Output Test Circuit and Voltage Waveform



#### PARAMETER MEASUREMENT INFORMATION





#### **VOLTAGE WAVEFORMS**

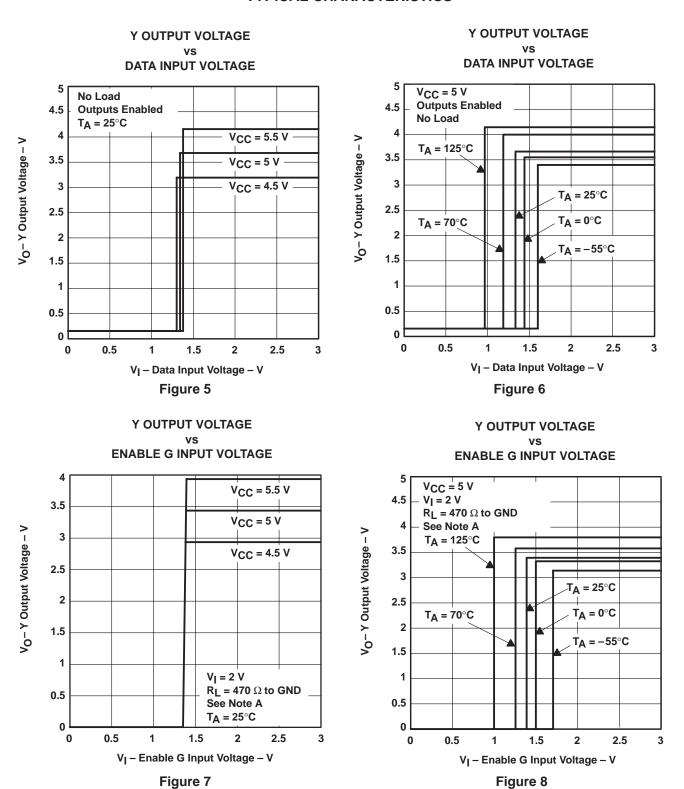
NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $t_{\Gamma} \le 5$  ns,  $t_{\tilde{f}} \le 5$  ns, PRR  $\le 1$  MHz, duty cycle  $\le 50\%$ ,  $Z_{\tilde{O}} \approx 50~\Omega$ .

- B. C<sub>I</sub> includes probe and stray capacitance.
- C. All diodes are 1N916 or 1N3064.

Figure 4. Driver Test Circuit and Voltage Waveforms



### TYPICAL CHARACTERISTICS†



† Data for temperatures below 0°C and above 70°C are applicable to the SN55ALS194 circuits only.

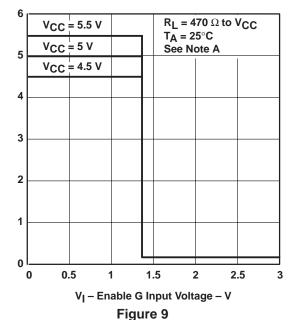
NOTE A: The A input is connected to V<sub>CC</sub> during the testing of the Y outputs and to GND during the testing of the Z outputs.



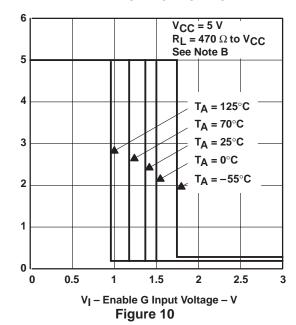
#### TYPICAL CHARACTERISTICS<sup>†</sup>

V<sub>O</sub>-Z Output Voltage - V

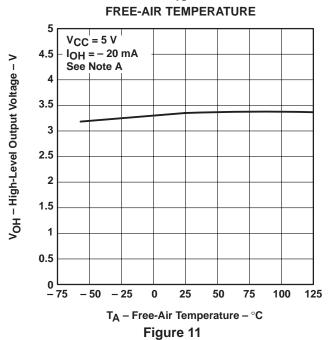
## **Z OUTPUT VOLTAGE ENABLE G INPUT VOLTAGE**



**Z OUTPUT VOLTAGE ENABLE G INPUT VOLTAGE** 



# HIGH-LEVEL OUTPUT VOLTAGE



### HIGH-LEVEL OUTPUT VOLTAGE **HIGH-LEVEL OUTPUT CURRENT**

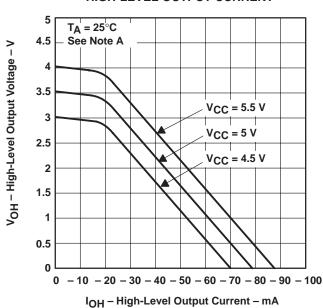


Figure 12

† Data for temperatures below 0°C and above 70°C are applicable to the SN55ALS194 circuits only.

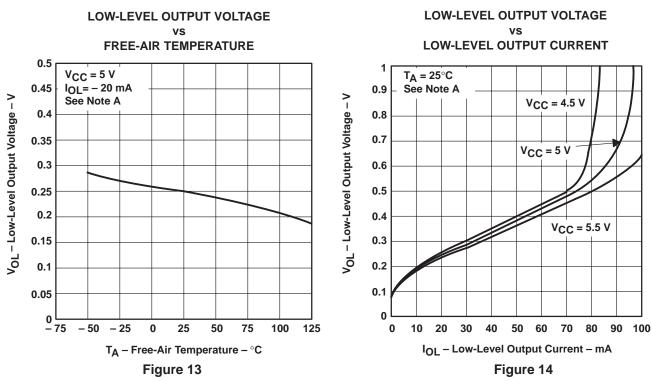
NOTES: A. The A input is connected to VCC during the testing of the Y outputs and to GND during the testing of the Z outputs.

B. The A input is connected to ground during the testing of the Y outputs and to V<sub>CC</sub> during the testing of the Z outputs.

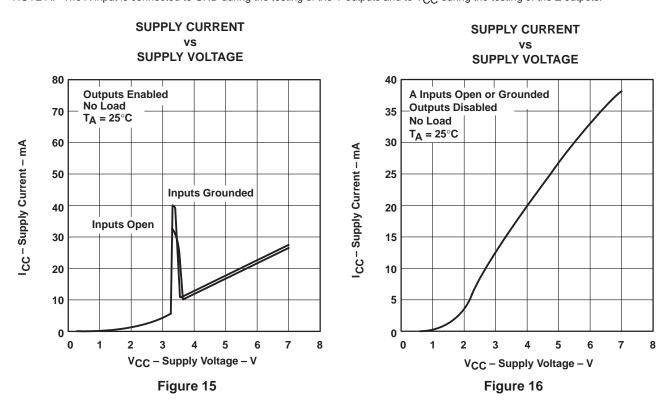


V<sub>O</sub>- Z Output Voltage - V

#### TYPICAL CHARACTERISTICS†



NOTE A: The A input is connected to GND during the testing of the Y outputs and to V<sub>CC</sub> during the testing of the Z outputs.



<sup>†</sup> Data for temperatures below 0°C and above 70°C are applicable to the SN55ALS194 circuits only.



### TYPICAL CHARACTERISTICS

### SUPPLY CURRENT vs FREQUENCY

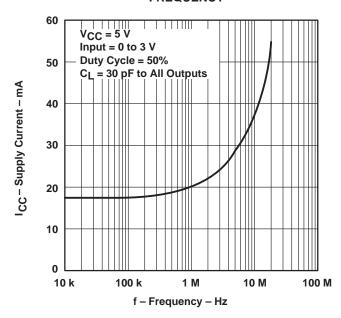


Figure 17

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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN75ALS194D	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS194	Samples
SN75ALS194DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS194	Samples
SN75ALS194N	LIFEBUY	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75ALS194N	
SN75ALS194NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS194	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: Til defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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### **PACKAGE OPTION ADDENDUM**

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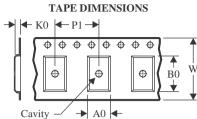
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





	· · · · · · · · · · · · · · · · · · ·
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75ALS194DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75ALS194NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1

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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75ALS194DR	SOIC	D	16	2500	340.5	336.1	32.0
SN75ALS194NSR	SO	NS	16	2000	356.0	356.0	35.0

### **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN75ALS194D	D	SOIC	16	40	507	8	3940	4.32
SN75ALS194N	N	PDIP	16	25	506	13.97	11230	4.32



SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



### NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



### D (R-PDS0-G16)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



# D (R-PDSO-G16)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



### **MECHANICAL DATA**

### NS (R-PDSO-G\*\*)

## 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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